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Vishay Semiconductors

AAP Gen 7 (TO-240AA) Power Modules Standard Diodes, 80 A



AAP Gen 7 (TO-240AA)

| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|--|--|--|--|--|
| I _{F(AV)} | 80 A | | | | |
| Туре | Modules - Diode, High Voltage | | | | |
| Package | AAP Gen 7 (TO-240AA) | | | | |
| Circuit configuration | Two diodes doubler circuit, two diodes common cathode, two diodes common anode, single diode | | | | |

MECHANICAL DESCRIPTION

The AAP Gen 7 (TO-240AA), new generation of AAP module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- High voltage
- Industrial standard package
- Low thermal resistance



- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-----------------|-------------|--------------------|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | |
| 1 | | 80 | A | | |
| IF(AV) | T _C | 110 | °C | | |
| I _{F(RMS)} | | 126 | | | |
| 1 | 50 Hz | 1500 | A | | |
| IFSM | 60 Hz | 1570 | | | |
| l ² t | 50 Hz | 11.25 | kA ² s | | |
| 1-1 | 60 Hz | 10.26 | KA-S | | |
| l²√t | | 112.5 | kA ² √s | | |
| V _{RRM} | Range | 400 to 1600 | V | | |
| T _{Stg} , T _J | | -40 to +150 | °C | | |

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ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | | |
|-----------------|-----------------|--|--|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} MAXIMUM AT T _J = 150 °C mA | | | |
| | 04 | 400 | 500 | | | | |
| | 06 | 600 | 700 | | | | |
| | 08 | 800 | 900 | | | | |
| VS-VSK.71 | 10 | 1000 | 1100 | 10 | | | |
| | 12 | 1200 | 1300 | | | | |
| | 14 | 1400 | 1500 | | | | |
| | 16 | 1600 | 1700 | | | | |

| FORWARD CONDUCTION | | | | | | |
|---|---------------------|--|---|---|--------|--------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | | VALUES | UNITS |
| Maximum average forward current at case temperature | I _{F(AV)} | 180° condu | 180° conduction, half sine wave | | | A °C |
| Maximum RMS forward current | I _{F(RMS)} | | | | 126 | |
| | | t = 10 ms | No voltage | | 1500 | |
| Maximum peak, one-cycle forward, | | t = 8.3 ms | reapplied | | 1570 | А |
| non-repetitive surge current | I _{FSM} | t = 10 ms | 100 % V _{RRM} | | 1260 | |
| | | t = 8.3 ms | reapplied | Sinusoidal half wave, | 1320 | |
| | l ² t | t = 10 ms | No voltage | initial $T_J = T_J$ maximum | 11.25 | |
| Maximum I ² t for fusing | | t = 8.3 ms | reapplied | | 10.26 | kA ² s |
| Maximum 1-t for fusing | | t = 10 ms | 100 % V _{RRM} | | 7.95 | KA-S |
| | | t = 8.3 ms | reapplied | | 7.23 | |
| Maximum I ² \sqrt{t} for fusing | l²√t | t = 0.1 ms t | o 10 ms, no vol | tage reapplied | 112.5 | kA ^{2√} s |
| Low level value of threshold voltage | V _{F(TO)1} | (16.7 % x π | $x I_{F(AV)} < I < \pi x$ | I _{F(AV)}), T _J = T _J maximum | 0.73 | V |
| High level value of threshold voltage | V _{F(TO)2} | $(I > \pi \times I_{F(AV)})$ | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ | | | v |
| Low level value of forward slope resistance | r _{f1} | (16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum | | | 3.22 | mΩ |
| High level value of forward slope resistance | r _{f2} | $(I > \pi x I_{F(AV)}), T_J = T_J maximum$ | | | 2.89 | 11152 |
| Maximum forward voltage drop | V _{FM} | $I_{FM} = \pi \times I_{F(r)}$ | _{AV)} , T _J = 25 °C, 1 | t _p = 400 μs square wave | 1.6 | V |

| BLOCKING | | | | | | |
|---|------------------|-------------------------|----------------------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum peak reverse leakage current | I _{RRM} | T _J = 150 °C | 10 | mA | | |
| Maximum RMS insulation voltage | V _{INS} | 50 Hz | 3000 (1 min) 3600 (1 s) | V | | |



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| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|---|---------------|-----------------------------------|---|-------------|------------|--|
| PARAMETER | | SYMBOL | BOL TEST CONDITIONS | | UNITS | |
| Junction and storage temp | erature range | T _J , T _{Stg} | | -40 to +150 | °C | |
| Maximum internal thermal junction to case per leg | resistance, | R _{thJC} | DC operation | 0.28 | | |
| Typical thermal resistance, case to heatsink per module | | R _{thCS} | Mounting surface flat, smooth and greased | 0.1 | °C/W | |
| | to heatsink | | A mounting compound is recommended and the | 4 | | |
| Mounting torque ± 10 % busbar | | | torque should be rechecked after a period of 3 hours to allow for the spread of the compound. | 3 | Nm | |
| Approximate weight | | | | 75 | g | |
| Approximate weight | | | | 2.7 | oz. | |
| Case style | | | JEDEC® | AAP Gen 7 | (TO-240AA) | |

| DEVICES | SINE HALF WAVE CONDUCTION | | | | | RECTANGULAR WAVE CONDUCTION | | | | | |
|---------|---------------------------|-------|-------|-------|-------|-----------------------------|-------|------|-------|------|-------|
| DEVICES | 180° | 120° | 90° | 60° | 30° | 180° | 120° | 90° | 60° | 30° | UNITS |
| VSK.71 | 0.075 | 0.088 | 0.113 | 0.155 | 0.228 | 0.06 | 0.094 | 0.12 | 0.158 | 0.23 | °C/W |

Note

Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

Maximum average forward power loss (W)

160

140

120

100

80

60

40

20

0

1400

1200

1000

800

600

0

1^{80°} 120

90

60 30°

RMS limi

20

40 60 80

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DC

Ø

Conduction Period

100 120

_Initial Tj = Tj max

@ 60 Hz 0.0083 s @ 50 Hz 0.0100s

140

100

Per leg, Tj = 150°C

Average forward current (A)

Fig. 4 - Foward Power Loss Characteristics

At any rated load condition and with

rated Vrrm applied following surge

10

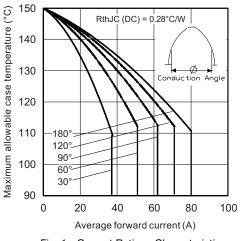
Versus Pulse Train Duration

Initial Tj = 150°C

No Voltage Reapplied

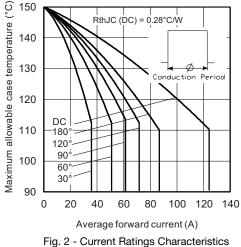
Rated Vrrm reapplied

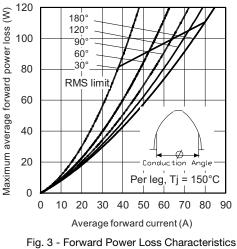
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Fig. 1 - Current Ratings Characteristics

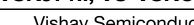


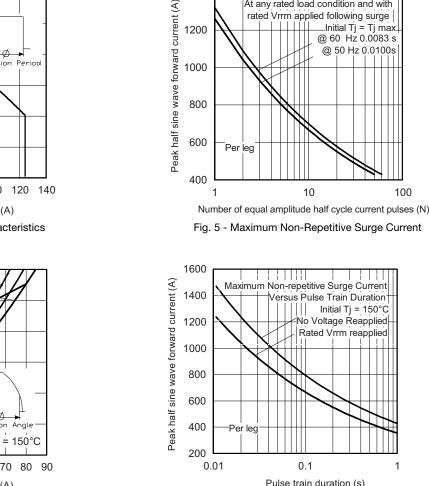


1000 800 600 400 Per lec 200 0.1 0.01

Pulse train duration (s)

Fig. 6 - Maximum Non-Repetitive Surge Current



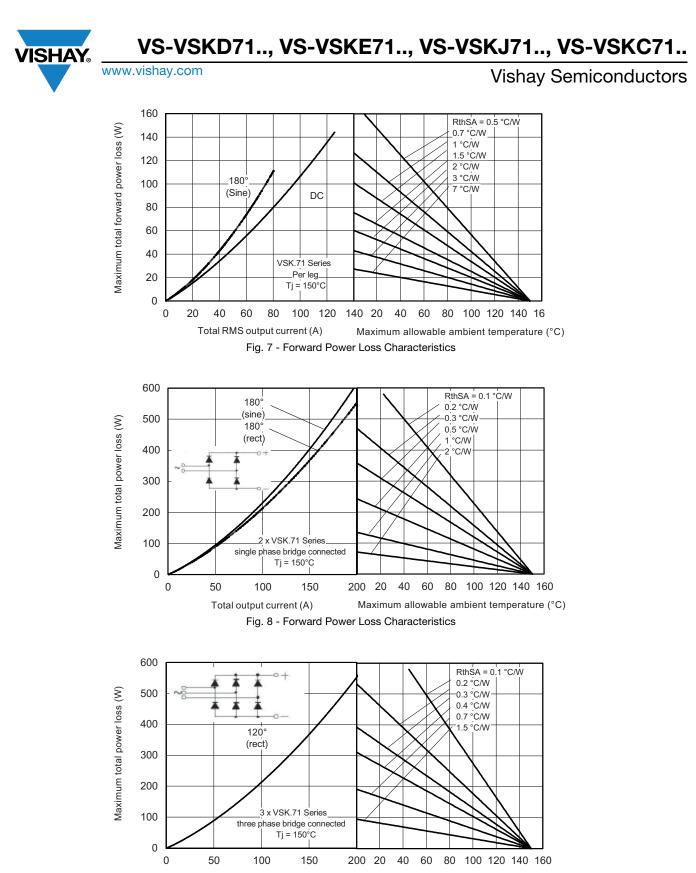


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Total output current (A) Maximum allowable ambient temperature (°C)

Fig. 9 - Forward Power Loss Characteristics



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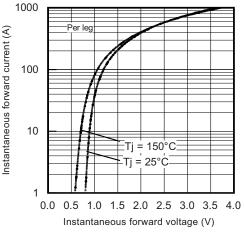


Fig. 10 - Forward Voltage Characteristics

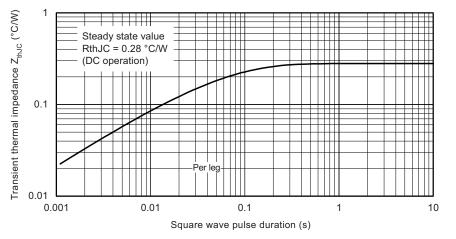


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

VS-VS **Device code** Κ D 71 1 16 2 (3) (4) 1 5 Vishay Semiconductors product 2 Module type 3 Circuit configuration (see Circuit Configuration table) 4 Current code (80 A) 5 Voltage code (see Voltage Ratings table)

Note

• To order the optional hardware go to www.vishay.com/doc?95172

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| CIRCUIT CONFIGURATION | | | | | |
|----------------------------|-------------------------------|-----------------|--|--|--|
| CIRCUIT DESCRIPTION | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING | | | |
| Two diodes doubler circuit | D | | | | |
| Two diodes common cathode | С | | | | |
| Two diodes common anode | J | | | | |
| Single diode | E | | | | |

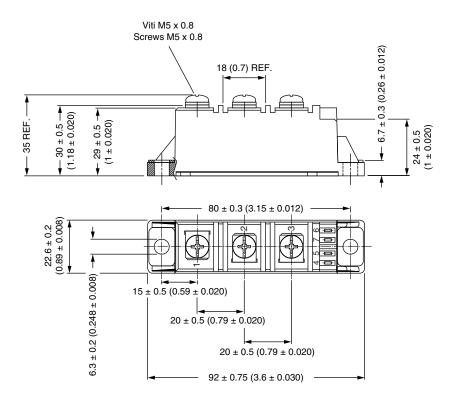
| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95369 | | | |

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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